

Data Sheet August 29, 2007 FN6549.1

# +1.8V to +5.5V, $5\Omega$ , Single SPDT Analog Switch

The Intersil ISL54500 device is a low ON-resistance, low voltage, bidirectional, single pole/double throw (SPDT) analog switch designed to operate from a single +1.8V to +5.5V supply. Targeted applications include battery powered equipment that benefit from low ON-resistance and fast switching speeds ( $t_{ON}$  = 22ns,  $t_{OFF}$  = 15ns). The digital logic input is 1.8V CMOS compatible when using a single +3V supply.

Cell phones, for example, often face ASIC functionality limitations. The number of analog input or GPIO pins may be limited and digital geometries are not well suited to analog switch performance. This part may be used to "mux-in" additional functionality while reducing ASIC design risk. The ISL54500 is offered in the 6 Ld 1.2mmx1.0mmx0.4mm pitch  $\mu TDFN$  package, alleviating board space limitations.

The ISL54500 is a committed SPDT that consist of one normally open (NO) and one normally closed (NC) switch. This configuration can also be used as a 2-to-1 multiplexer.

**TABLE 1. FEATURES AT A GLANCE** 

	ISL54500		
Number of Switches	1		
SW	SPDT or 2-1 MUX		
1.8V r <sub>ON</sub>	12Ω		
1.8V t <sub>ON</sub> /t <sub>OFF</sub>	70ns/52ns		
3V r <sub>ON</sub>	6.0Ω		
3V t <sub>ON</sub> /t <sub>OFF</sub>	30ns/20ns		
5V r <sub>ON</sub>	5.0Ω		
5V t <sub>ON</sub> /t <sub>OFF</sub>	22ns/15ns		
Package	6 Ld μTDFN		

#### Features

<ul> <li>ON-resistance (r<sub>ON</sub>)</li> </ul>
- $V_{CC} = +5.0V$
- $V_{CC} = +3.0V$
- $V_{CC} = +1.8V$
• $r_{\mbox{ON}}$ matching between channels
• $r_{\mbox{ON}}$ flatness (+4.5V Supply)
• Single supply operation +1.8V to +5.5V
• Fast switching action (+4.5V Supply)
- t <sub>ON</sub>
- t <sub>OFF</sub>
toff
Guaranteed break-before-make

#### **Applications**

- · Battery powered, handheld, and portable equipment
  - Cellular/mobile phones
  - Pagers
  - Laptops, notebooks, palmtops

Pb-free available (RoHS compliant)

- Portable Test and Measurement
- Medical Equipment
- · Audio and video switching

#### Related Literature

 Technical Brief TB363 "Guidelines for Handling and Processing Moisture Sensitive Surface Mount Devices (SMDs)"

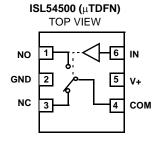
### **Ordering Information**

PART NUMBER (Note)	PART MARKING	TEMP. RANGE (°C)	PACKAGE (Pb-Free)	PKG. DWG. #
ISL54500IRUZ-T*	0	-40 to +85	6 Ld μTDFN (Tape and Reel)	L6.1.2x1.0A

<sup>\*</sup>Please refer to TB347 for details on reel specifications.

NOTE: These Intersil Pb-free plastic packaged products employ special Pb-free material sets; molding compounds/die attach materials and NiPdAu plate - e4 termination finish, which is RoHS compliant and compatible with both SnPb and Pb-free soldering operations. Intersil Pb-free products are MSL classified at Pb-free peak reflow temperatures that meet or exceed the Pb-free requirements of IPC/JEDEC J STD-020.

#### Pinout (Note 1)



#### NOTE:

1. Switches Shown for Logic "0" Input.

### Pin Descriptions

NAME	PIN	FUNCTION
V+	5	System Power Supply Input (+1.8V to +5.5V)
GND	2	Ground Connection
IN	6	Digital Control Input
СОМ	4	Analog Switch Common Pin
NO	1	Analog Switch Normally Open Pin
NC	3	Analog Switch Normally Closed Pin

## Truth Table

LOGIC	PIN NC	PIN NO
0	ON	OFF
1	OFF	ON

NOTE: Logic "0"  $\leq$ 0.5V. Logic "1"  $\geq$ 1.4V with a 3V supply.

#### **Absolute Maximum Ratings**

V+ to GND0.5 to 6.5V
Input Voltages
NO, NC, IN (Note 2)0.5 to ((V+) + 0.5V)
Output Voltages
COM (Note 2)0.5 to ((V+) + 0.5V)
Continuous Current NO, NC, or COM ±300mA
Peak Current NO, NC, or COM
(Pulsed 1ms, 10% Duty Cycle, Max) ±500mA
ESD Rating:
Human Body Model
Machine Model
Charged Device Model

#### **Thermal Information**

Thermal Resistance (Typical, Notes 3, 4)  $~\theta_{JA}$  (°C/W)  $~\theta_{JC}$  (°C/W) 6 Ld μTDFN Package ..... Maximum Junction Temperature (Plastic Package). . . . . . +150°C Maximum Storage Temperature Range . . . . . . -65°C to +150°C Pb-free reflow profile . . . . . . . . . . . . . . . . see link below http://www.intersil.com/pbfree/Pb-FreeReflow.asp

#### **Operating Conditions**

V+ (Positive DC Supply Voltage)	1.8V to 5.5V
Analog Signal Range	0V to V+
V <sub>IN</sub> (Digital Logic Input Voltage (IN)	0V to V+
Temperature Range	
ISL54500IRUZ4	0°C to +85°C

CAUTION: Do not operate at or near the maximum ratings listed for extended periods of time. Exposure to such conditions may adversely impact product reliability and result in failures not covered by warranty.

- 2. Signals on NC, NO, IN, or COM exceeding V+ or GND are clamped by internal diodes. Limit forward diode current to maximum current ratings.
- 3.  $\theta_{JA}$  is measured in free air with the component mounted on a high effective thermal conductivity test board with "direct attach" features. See Tech Brief TB379.
- 4. For  $\theta_{\rm JC}$ , the "case temp" location is the center of the exposed metal pad on the package underside.

### **Electrical Specifications - 5V Supply**

Test Conditions: V+ = +4.5V to +5.5V, GND = 0V,  $V_{INH}$  = 2.0V,  $V_{INL}$  = 0.8V (Note 5), Unless Otherwise Specified.

PARAMETER	TEST CONDITIONS	TEMP (°C)	MIN (Notes 6, 7)	TYP	MAX (Notes 6, 7)	UNITS
ANALOG SWITCH CHARACTERIS	TICS				•	
Analog Signal Range, V <sub>ANALOG</sub>		Full	0	-	V+	V
ON-Resistance, r <sub>ON</sub>	$V+ = 4.5V$ , $I_{COM} = 100$ mA, $V_{NO}$ or $V_{NC} = 0V$ to $V+$ ,	25 - 4.2 5	5	Ω		
	(Note 9, See Figure 5)	Full	-	-	6	Ω
r <sub>ON</sub> Matching Between Channels,	$V+ = 4.5V$ , $I_{COM} = 100$ mA, $V_{NO}$ or $V_{NC} = 2.5V$	25 - 0.046 0.2	0.2	Ω		
Δron	(Note 9)	Full	-	-	0.3	Ω
r <sub>ON</sub> Flatness, r <sub>FLAT(ON)</sub>	$V+ = 4.5V$ , $I_{COM} = 100$ mA, $V_{NO}$ or $V_{NC} = 0V$ to $V+$ ,	25	-	1.1	1.3	Ω
	(Notes 8, 9)	Full	-	-	1.5	Ω
NO or NC OFF Leakage Current,	$V+ = 5.5V$ , $V_{COM} = 0.3V$ , 5V, $V_{NO}$ or $V_{NC} = 5V$ , 0.3V	25	-25	1.2	25	nA
INO(OFF) or INC(OFF)	!		-150	-	150	nA
COM ON Leakage Current,	$V + = 5.5V$ , $V_{COM} = 0.3V$ , 5V, or $V_{NO}$ or	25	-30	1.7	30	nA
ICOM(ON)	$V_{NC} = 0.3V$ , 5V, or Floating	Full	-300	-	300	nA
DYNAMIC CHARACTERISTICS						
Turn-ON Time, t <sub>ON</sub>	$V + = 4.5V$ , $V_{NO}$ or $V_{NC} = 3.0V$ , $R_L = 50\Omega$ ,	25	-	22	-	ns
	C <sub>L</sub> = 35pF (See Figure 1, Note 9)	Full	-	23	-	ns
Turn-OFF Time, t <sub>OFF</sub>	V+ = 4.5V, $V_{NO}$ or $V_{NC}$ = 3.0V, $R_L$ = 50 $\Omega$ , $C_L$ = 35pF (See Figure 1, Note 9)	25	-	15	-	ns
		Full	-	15	-	ns
Break-Before-Make Time Delay, t <sub>D</sub>	V+ = 5.5V, $V_{NO}$ or $V_{NC}$ = 3.0V, $R_L$ = 50 $\Omega$ , $C_L$ = 35pF (See Figure 3, Note 9)	Full	-	18	-	ns
Charge Injection, Q	$V_G = 0V$ , $R_G = 0\Omega$ , $C_L = 1.0$ nF (See Figure 2)	25	-	16	-	рС
OFF Isolation	$R_L = 50\Omega$ , $C_L = 5pF$ , $f = 1MHz$ , $V_{COM} = 1V_{P-P}$ (See Figure 4)	25	-	75	-	dB
Total Harmonic Distortion	f = 20Hz to 20kHz, $V_{COM} = 2V_{P-P}$ , $R_L = 32\Omega$	25	-	0.12	-	%
Total Harmonic Distortion	f = 20Hz to 20kHz, $V_{COM}$ = $2V_{P-P}$ , $R_L$ = $600\Omega$	25	-	0.01	-	%
-3dB Bandwidth	Signal = 0dBm, $R_L = 50\Omega$	25	-	350	-	MHz
NO or NC OFF Capacitance, C <sub>OFF</sub>	$V+ = 4.5V$ , $f = 1MHz$ , $V_{NO}$ or $V_{NC} = V_{COM} = 0V$ (See Figure 7)	25	-	6	-	pF

intersil FN6549.1 August 29, 2007

3

### **Electrical Specifications - 5V Supply**

Test Conditions: V+ = +4.5V to +5.5V, GND = 0V,  $V_{INH}$  = 2.0V,  $V_{INL}$  = 0.8V (Note 5), Unless Otherwise Specified. (Continued)

PARAMETER	TEST CONDITIONS	TEMP (°C)	MIN (Notes 6, 7)	TYP	MAX (Notes 6, 7)	UNITS
COM ON Capacitance, C <sub>COM(ON)</sub>	$V+ = 4.5V$ , $f = 1MHz$ , $V_{NO}$ or $V_{NC} = V_{COM} = 0V$ (See Figure 7)	25	-	12	-	pF
POWER SUPPLY CHARACTERIST	rics		•			
Power Supply Range		Full	1.8	-	5.5	V
Positive Supply Current, I+	V+ = 5.5V, V <sub>IN</sub> = 0V or V+	25	-	0.02	0.1	μΑ
		Full	-	0.5	2.5	μΑ
DIGITAL INPUT CHARACTERISTIC	S		1		1	
Input Voltage Low, V <sub>INL</sub>		Full	-	-	0.8	V
Input Voltage High, V <sub>INH</sub>		Full	2.4	-	-	V
Input Current, I <sub>INH</sub> , I <sub>INL</sub>	V+ = 5.5V, V <sub>IN</sub> = 0V or V+	Full	-0.1	0.044	0.1	μΑ

#### **Electrical Specifications - 3V Supply**

Test Conditions: V+ = +2.7V to +3.6V, GND = 0V,  $V_{INH}$  = 1.4V,  $V_{INL}$  = 0.5V (Note 5), Unless Otherwise Specified.

PARAMETER	TEST CONDITIONS	TEMP (°C)	MIN (Notes 6, 7)	TYP	MAX (Notes 6, 7)	UNITS
ANALOG SWITCH CHARACTERIS		( - /	(**************************************		(**************************************	
Analog Signal Range, V <sub>ANALOG</sub>		Full	0	-	V+	V
ON-Resistance, r <sub>ON</sub>	$V+ = 2.7V$ , $I_{COM} = 100$ mA, $V_{NO}$ or $V_{NC} = 0V$ to $V+$ ,	25	-	6.3	7	Ω
	(Note 9, See Figure 5)	Full	-	-	8	Ω
r <sub>ON</sub> Matching Between Channels,	V+ = 2.7V, I <sub>COM</sub> = 100mA, V <sub>NO</sub> or V <sub>NC</sub> = 1.5V	25	-	0.05	0.3	Ω
$\Delta r_{ON}$	(Note 9)	Full	-	-	0.4	Ω
r <sub>ON</sub> Flatness, r <sub>FLAT(ON)</sub>	$V+ = 2.7V$ , $I_{COM} = 100$ mA, $V_{NO}$ or $V_{NC} = 0V$ to $V+$ ,	/+, 25 - 1.8	2.3	Ω		
	(Notes 8, 9)	Full	-	-	2.5	Ω
DYNAMIC CHARACTERISTICS						
Turn-ON Time, t <sub>ON</sub>	$V + = 2.7V$ , $V_{NO}$ or $V_{NC} = 1.5V$ , $R_L = 50\Omega$ ,	25	-	28	-	ns
	C <sub>L</sub> = 35pF (See Figure 1, Note 9)	Full	-	30	-	ns
Turn-OFF Time, t <sub>OFF</sub>	$V+ = 2.7V$ , $V_{NO}$ or $V_{NC} = 1.5V$ , $R_L = 50\Omega$ ,	25	-	20	-	ns
	C <sub>L</sub> = 35pF (See Figure 1, Note 9)	Full	-	30	-	ns
Break-Before-Make Time Delay, t <sub>D</sub>	V+ = 3.0V, $V_{NO}$ or $V_{NC}$ = 1.5V, $R_L$ = 50 $\Omega$ , $C_L$ = 35pF (See Figure 3, Note 9)	Full	-	22	-	ns
Charge Injection, Q	$V_G = 0V$ , $R_G = 0\Omega$ , $C_L = 1.0$ nF (See Figure 2)	25	-	12	-	рС
OFF Isolation	$R_L = 50\Omega$ , $C_L = 5pF$ , $f = 1MHz$ , $V_{COM} = 1V_{P-P}$ (See Figure 4)	25	-	75	-	dB
Total Harmonic Distortion	$f = 20Hz$ to $20kHz$ , $V_{COM} = 2V_{P-P}$ , $R_L = 32\Omega$	25	-	0.4	-	%
Total Harmonic Distortion	$f = 20Hz$ to $20kHz$ , $V_{COM} = 2V_{P-P}$ , $R_L = 600\Omega$	25	-	0.053	-	%
-3dB Bandwidth	Signal = 0dBM, $R_L = 50\Omega$	25	-	350	-	MHz
NO or NC OFF Capacitance, COFF	$f = 1MHz$ , $V_{NO}$ or $V_{NC} = V_{COM} = 0V$ (See Figure 7)	25	-	6	-	pF
COM ON Capacitance, C <sub>COM(ON)</sub>	$f = 1MHz$ , $V_{NO}$ or $V_{NC} = V_{COM} = 0V$ (See Figure 7)	25	-	12	-	pF
POWER SUPPLY CHARACTERIST	TICS					
Positive Supply Current, I+	$V+ = 3.6V$ , $V_{IN} = 0V$ or $V+$	25	-	0.02	-	μА
		Full	-	0.11	-	μΑ
DIGITAL INPUT CHARACTERISTIC	es					
Input Voltage Low, V <sub>INL</sub>		Full	-	-	0.5	V
Input Voltage High, V <sub>INH</sub>		Full	1.4	-	-	V
Input Current, I <sub>INH</sub> , I <sub>INL</sub>	V+ = 3.6V, V <sub>IN</sub> = 0V or V+	Full	-0.1	0.049	0.1	μΑ

#### **Electrical Specifications - 1.8V Supply**

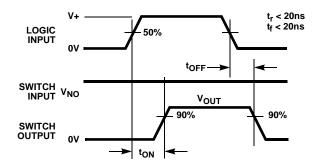
Test Conditions: V+=+1.8V, GND = 0V,  $V_{INH}=1V$ ,  $V_{INL}=0.4V$  (Note 5), Unless Otherwise Specified.

PARAMETER	TEST CONDITIONS		MIN (Notes 6, 7)	TYP	MAX (Notes 6, 7)	UNITS
ANALOG SWITCH CHARACTERIS	STICS	Į.			1	
Analog Signal Range, V <sub>ANALOG</sub>		Full	0	=	V+	V
ON-Resistance, r <sub>ON</sub>	$V + = 1.8V$ , $I_{COM} = 10$ mA, $V_{NO}$ or $V_{NC} = 0V$ to $V +$ ,	25	-	11.9	12.8	Ω
	(Note 9, See Figure 5)	Full	-	-	13.8	Ω
DYNAMIC CHARACTERISTICS						
Turn-ON Time, t <sub>ON</sub>	$V+ = 1.8V$ , $V_{NO}$ or $V_{NC} = 1.5V$ , $R_L = 50\Omega$ ,	25	-	70	-	ns
	C <sub>L</sub> = 35pF (See Figure 1, Note 9)	Full	-	130	-	ns
Turn-OFF Time, t <sub>OFF</sub>	V+ = 1.8V, $V_{NO}$ or $V_{NC}$ = 1.5V, $R_L$ = 50 $\Omega$ , $C_L$ = 35pF (See Figure 1, Note 9)	25	-	52	-	ns
		Full	-	100	-	ns
Break-Before-Make Time Delay, t <sub>D</sub>	V+ = 1.8V, $V_{NO}$ or $V_{NC}$ = 1.5V, $R_L$ = 50Ω, $C_L$ = 35pF (See Figure 3, Note 9)	Full	-	42	-	ns
Charge Injection, Q	$V_G = 0$ , $R_G = 0\Omega$ , $C_L = 1.0$ nF (See Figure 2)	25	-	5.8	-	рC
DIGITAL INPUT CHARACTERISTIC	DIGITAL INPUT CHARACTERISTICS					
Input Voltage Low, VINL		Full	-	-	0.4	V
Input Voltage High, V <sub>INH</sub>		Full	1	-	-	V

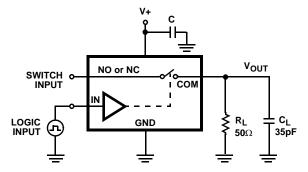
#### NOTES:

- 5.  $V_{IN}$  = input voltage to perform proper function.
- 6. The algebraic convention, whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet.
- 7. Parts are 100% tested at +25°C. Over-temperature limits established by characterization and are not production tested.
- 8. Flatness is defined as the difference between maximum and minimum value of on-resistance over the specified analog signal range.
- 9. Limits established by characterization and are not production tested.

#### Test Circuits and Waveforms



Logic input waveform is inverted for switches that have the opposite logic sense.



Repeat test for all switches. C<sub>L</sub> includes fixture and stray capacitance.

$$V_{OUT} = V_{(NO \text{ or NC})} \frac{R_L}{R_L + r_{(ON)}}$$

FIGURE 1A. MEASUREMENT POINTS

FIGURE 1B. TEST CIRCUIT

FIGURE 1. SWITCHING TIMES

### Test Circuits and Waveforms (Continued)

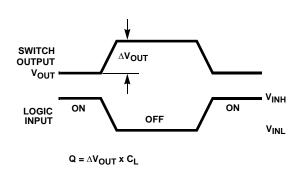


FIGURE 2A. MEASUREMENT POINTS

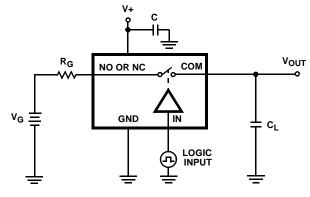


FIGURE 2B. TEST CIRCUIT

FIGURE 2. CHARGE INJECTION

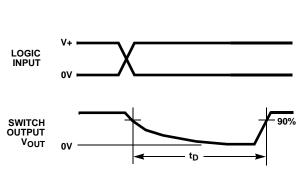
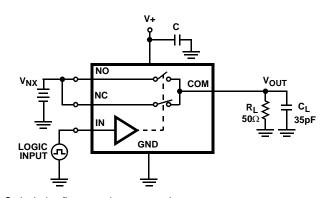


FIGURE 3A. MEASUREMENT POINTS



 $\ensuremath{C_L}$  includes fixture and stray capacitance.

FIGURE 3B. TEST CIRCUIT

FIGURE 3. BREAK-BEFORE-MAKE TIME

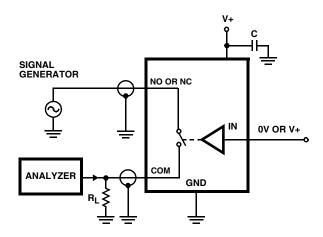


FIGURE 4. OFF ISOLATION TEST CIRCUIT

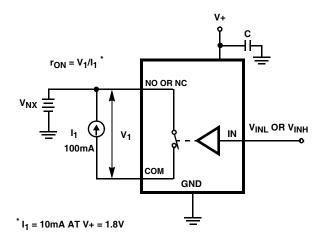


FIGURE 5.  $r_{\mbox{ON}}$  TEST CIRCUIT

#### Test Circuits and Waveforms (Continued)

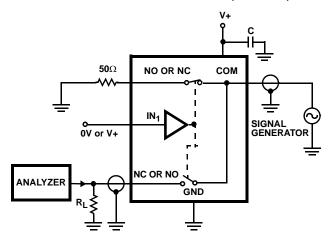


FIGURE 6. CROSSTALK TEST CIRCUIT

#### **Detailed Description**

The ISL54500 is a bi-directional, single pole/double throw (SPDT) analog switch that offers precise switching capability from a single 1.8V to 5.5V supply with low ON-resistance (5 $\Omega$ ) and high speed operation (t<sub>ON</sub> = 22ns, t<sub>OFF</sub> = 15ns). The device is especially well suited for portable battery powered equipment due to its low operating supply voltage (1.8V), low power consumption (0.11 $\mu$ W), low leakage currents (300nA max) and small  $\mu$ TDFN package. The low ON-resistance and r<sub>ON</sub> flatness provide very low insertion loss and distortion to application that require signal reproduction.

#### External V+ Series Resistor

For improved ESD and latch-up immunity Intersil recommends adding a  $100\Omega$  resistor in series with the V+ power supply pin of the ISL54050 IC (see Figure 8).

During an overvoltage transient event (such as occurs during system level IEC 61000 ESD testing), substrate currents can be generated in the IC that can trigger parasitic SCR structures to turn ON, creating a low impedance path from the V+ power supply to ground. This will result in a significant amount of current flow in the IC, which can potentially create a latch-up state or permanently damage the IC. The external V+ resistor limits the current during this over-stress situation and has been found to prevent latch-up or destructive damage for many over voltage transient events.

Under normal operation, the sub-microamp  $I_{DD}$  current of the IC produces an insignificant voltage drop across the  $100\Omega$  series resistor resulting in no impact to switch operation or performance.

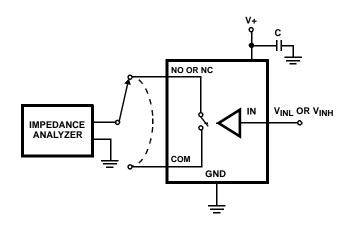


FIGURE 7. CAPACITANCE TEST CIRCUIT

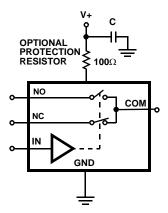


FIGURE 8. V+ SERIES RESISTOR FOR ENHANCED ESD AND LATCH-UP IMMUNITY

#### Supply Sequencing And Overvoltage Protection

With any CMOS device, proper power supply sequencing is required to protect the device from excessive input currents, which might permanently damage the IC. All I/O pins contain ESD protection diodes from the pin to V+ and to GND (see Figure 9). To prevent forward biasing these diodes, V+ must be applied before any input signals, and the input signal voltages must remain between V+ and GND.

If these conditions cannot be guaranteed then precautions must be implemented to prohibit the current and voltage at the logic pin and signal pins from exceeding the maximum ratings of the switch. The following two methods can be used to provide additional protection to limit the current in the event that the voltage at a signal pin or logic pin goes below ground or above the V+ rail.

Logic inputs can easily be protected by adding a  $1k\Omega$  resistor in series with the input (see Figure 9). The resistor limits the input current below the threshold that produces permanent damage, and the sub-microamp input current produces an insignificant voltage drop during normal operation.

FN6549.1 August 29, 2007 This method is not acceptable for the signal path inputs. Adding a series resistor to the switch input defeats the purpose of using a low  $r_{ON}$  switch. Connecting Schottky diodes to the signal pins (as shown in Figure 9) will shunt the fault current to the supply or to ground, thereby protecting the switch. These Schottky diodes must be sized to handle the expected fault current.

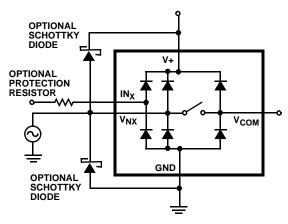


FIGURE 9. OVERVOLTAGE PROTECTION

#### **Power-Supply Considerations**

The ISL54500 construction is typical of most single supply CMOS analog switches, in that they have two supply pins: V+ and GND. V+ and GND drive the internal CMOS switches and set their analog voltage limits. Unlike switches with a 4V maximum supply voltage, the ISL54500 5.5V maximum supply voltage provides plenty of room for the 10% tolerance of 3.6V supplies, as well as room for overshoot and noise spikes.

The minimum recommended supply voltage is 1.8V but the part will operate with a supply below 1.8V. It is important to note that the input signal range, switching times, and ON-resistance degrade at lower supply voltages. Refer to the "Electrical Specifications" tables starting on page page 3 and the "Typical Performance Curves" starting on page 9 for details.

V+ and GND also power the internal logic and level shifters. The level shifters convert the input logic levels to switched V+ and GND signals to drive the analog switch gate terminals.

This family of switches cannot be operated with bipolar supplies because the input switching point becomes negative in this configuration.

#### Logic-Level Thresholds

This switch family is 1.8V CMOS compatible (0.5V and 1.4V) over a supply range of 2V to 3.6V (see Figure 16). At 3.6V the  $V_{IH}$  level is about 0.98V. This is still below the 1.8V CMOS guaranteed high output minimum level of 1.4V, but noise margin is reduced.

The digital input stages draw supply current whenever the digital input voltage is not at one of the supply rails. Driving the digital input signals from GND to V+ with a fast transition time minimizes power dissipation.

#### High-Frequency Performance

In  $50\Omega$  systems, the ISL54500 has a -3dB bandwidth of 350MHz (see Figure 17). The frequency response is very consistent over a wide V+ range, and for varying analog signal levels.

An OFF switch acts like a capacitor and passes higher frequencies with less attenuation, resulting in signal feedthrough from a switch's input to its output. Off isolation is the resistance to this feedthrough, while crosstalk indicates the amount of feedthrough from one switch to another. Figure 18 details the high off isolation provided by this family. At 1MHz, off isolation is about 75dB in  $50\Omega$  systems, decreasing approximately 20dB per decade as frequency increases. Higher load impedances decrease off isolation due to the voltage divider action of the switch OFF impedance and the load impedance.

#### Leakage Considerations

ESD protection diodes are internally connected between each analog-signal pin and both V+ and GND. One of these diodes conducts if any analog signal exceeds V+ or GND.

Virtually all the analog leakage current comes from the ESD diodes to V+ or GND. Although the ESD diodes on a given signal pin are identical and therefore fairly well balanced, they are reverse biased differently. Each is biased by either V+ or GND and the analog signal. This means their leakages will vary as the signal varies. The difference in the two diode leakages to the V+ and GND pins constitutes the analog-signal-path leakage current. All analog leakage current flows between each pin and one of the supply terminals, not to the other switch terminal. This is why both sides of a given switch can show leakage currents of the same or opposite polarity. There is no connection between the analog signal paths and V+ or GND.

### Typical Performance Curves T<sub>A</sub> = +25°C, Unless Otherwise Specified

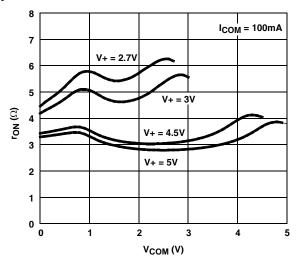


FIGURE 10. ON-RESISTANCE VS SUPPLY VOLTAGE VS SWITCH VOLTAGE

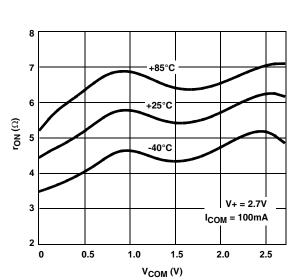


FIGURE 12. ON-RESISTANCE vs SWITCH VOLTAGE

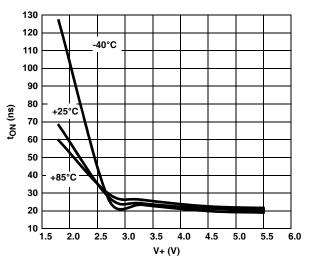


FIGURE 14. TURN-ON TIME vs SUPPLY VOLTAGE

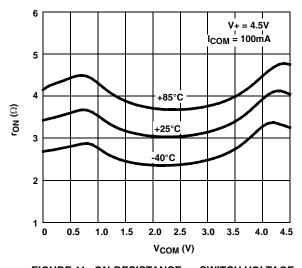


FIGURE 11. ON-RESISTANCE vs SWITCH VOLTAGE

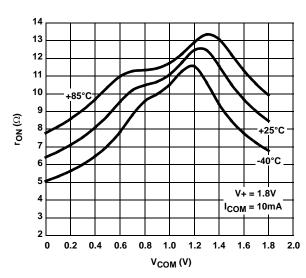


FIGURE 13. ON-RESISTANCE vs SWITCH VOLTAGE

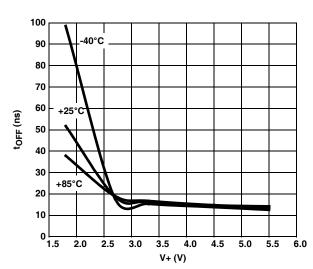


FIGURE 15. TURN-OFF TIME vs SUPPLY VOLTAGE

### **Typical Performance Curves** T<sub>A</sub> = +25°C, Unless Otherwise Specified (Continued)

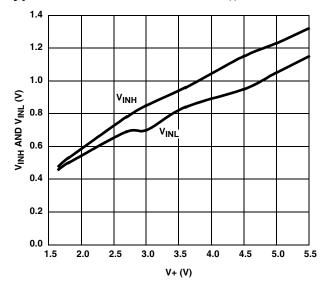


FIGURE 16. DIGITAL SWITCHING POINT vs SUPPLY VOLTAGE

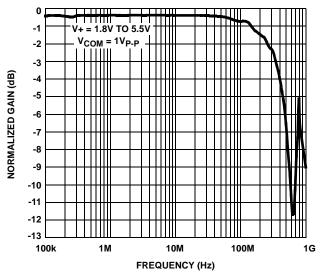


FIGURE 17. FREQUENCY RESPONSE

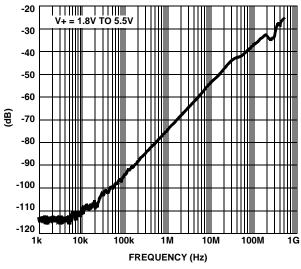


FIGURE 18. OFF ISOLATION

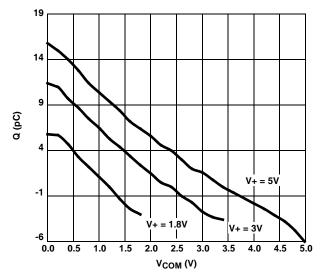


FIGURE 19. CHARGE INJECTION vs SWITCH VOLTAGE

#### Die Characteristics

SUBSTRATE POTENTIAL (POWERED UP):

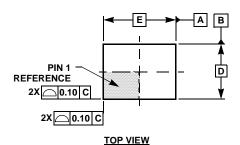
GND

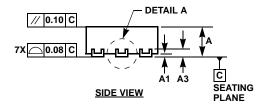
TRANSISTOR COUNT:

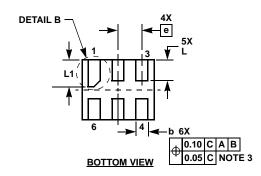
PROCESS:

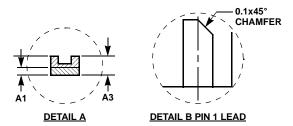
Submicron CMOS

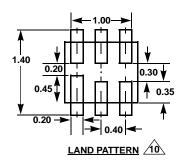
#### Ultra Thin Dual Flat No-Lead Plastic Package (UTDFN)











# **L6.1.2x1.0A**6 LEAD ULTRA THIN DUAL FLAT NO-LEAD PLASTIC PACKAGE

	N				
SYMBOL	MIN	NOMINAL	MAX	NOTES	
А	0.45	0.50	0.55	-	
A1	-	-	0.05	-	
А3		0.127 REF		-	
b	0.15	0.20	0.25	5	
D	0.95	1.00	1.05	-	
E	1.15	1.20	1.25	-	
е		0.40 BSC			
L	0.30	0.35	0.40	-	
L1	0.40	0.45	0.50	-	
N		2			
Ne		3			
θ	0	-	12	4	

Rev. 2 8/06

#### NOTES:

- 1. Dimensioning and tolerancing conform to ASME Y14.5-1994.
- 2. N is the number of terminals.
- 3. Ne refers to the number of terminals on E side.
- 4. All dimensions are in millimeters. Angles are in degrees.
- 5. Dimension b applies to the metallized terminal and is measured between 0.15mm and 0.30mm from the terminal tip.
- The configuration of the pin #1 identifier is optional, but must be located within the zone indicated. The pin #1 identifier may be either a mold or mark feature.
- 7. Maximum package warpage is 0.05mm.
- 8. Maximum allowable burrs is 0.076mm in all directions.
- 9. JEDEC Reference MO-255.
- For additional information, to assist with the PCB Land Pattern Design effort, see Intersil Technical Brief TB389.

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